

Amendments to the Claims:

Claims 1-8 (Canceled)

9. (Currently amended) A manufacturing method of a light emitting device comprising an anode, a cathode, a light emitting layer disposed between said anode and said cathode, and a hole injection layer disposed between said anode and said cathode, the method comprising:

forming said hole injection layer ~~[[by]]~~ that comprises phthalocyanine; and
exposing said hole injection layer to ~~gas-atmosphere~~ oxygen gas after forming said hole injection layer.

10. (Currently amended) The method according to claim ~~[[1]]~~ 9, wherein said phthalocyanine is copper phthalocyanine.

11. (Currently amended) The method according to claim 9, wherein an electron acceptable compound capable of oxidizing phthalocyanine is doped in said hole injection layer.

Claim 12 (Canceled)

Claim 13 (Canceled)

14. (Previously presented) The method according to claim 11, wherein said electron acceptable compound is TCNQ-F4 or V₂O₅.

15. (Currently amended) A light emitting device comprising:
an anode;
a cathode;
a light emitting layer disposed between said anode and said cathode; and
a hole injection layer disposed between said anode and said cathode,
wherein said hole injection layer includes phthalocyanine and is doped with an electron acceptable compound which oxidizes said phthalocyanine.

16. (Original) The light emitting device according to claim 15, wherein said electron acceptable compound is TCNQ-F4 or V_2O_5 .

17. (New) A manufacturing method of a light emitting device comprising an anode, a cathode, a light emitting layer disposed between said anode and said cathode, and a hole injection layer disposed between said anode and said cathode, the method comprising:

forming said hole injection layer that comprises phthalocyanine;

doping an electron acceptable compound capable of oxidizing phthalocyanine into said hole injection layer; and

exposing said hole injection layer to oxygen gas after forming said hole injection layer.

18. (New) The method according to claim 11, wherein said electron acceptable compound is TCNQ-F4 or V_2O_5 .

19. (New) A manufacturing method of a light emitting device comprising an anode, a cathode, a light emitting layer disposed between said anode and said cathode, and a hole injection layer disposed between said anode and said cathode, the method comprising:

forming said hole injection layer that comprises phthalocyanine in a first chamber of a multi-chamber system; and

exposing said hole injection layer to oxygen gas in a second chamber of the multi-chamber system after forming said hole injection layer,

wherein the multi-chamber system has at least the first chamber and the second chamber.

20. (New) An electronic equipment having the light emitting device according to claim 15, wherein the electronic equipment is selected from the group consisting of a display apparatus, a camera, an image reproducing apparatus, a portable type computer, a personal computer, a portable telephone, an audio equipment.